



## UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE  
 United States Patent and Trademark Office  
 Address: COMMISSIONER FOR PATENTS  
 P.O. Box 1450  
 Alexandria, Virginia 22313-1450  
 www.uspto.gov



Bib Data Sheet

CONFIRMATION NO. 1234

<b>SERIAL NUMBER</b> 09/805,273	<b>FILING OR 371(c) DATE</b> 03/13/2001 <b>RULE</b>	<b>CLASS</b> 438	<b>GROUP ART UNIT</b> 2823	<b>ATTORNEY DOCKET NO.</b> 9076/463	
<b>APPLICANTS</b> Wenge Yang, Fremont, CA;					
<b>** CONTINUING DATA *****</b> This appln claims benefit of 60/234,522 09/21/2000 and claims benefit of 60/234,523 09/21/2000 <i>MR</i>					
<b>** FOREIGN APPLICATIONS *****</b> <i>none MR</i>					
<b>IF REQUIRED, FOREIGN FILING LICENSE GRANTED</b> <b>** 05/14/2001</b>					
Foreign Priority claimed <input type="checkbox"/> yes <input checked="" type="checkbox"/> no 35 USC 119 (a-d) conditions <input type="checkbox"/> yes <input checked="" type="checkbox"/> no <input type="checkbox"/> Met after met Verified and Acknowledged <i>Michelle Estrada</i> Examiner's Signature Initials		<b>STATE OR COUNTRY</b> CA	<b>SHEETS DRAWING</b> 2	<b>TOTAL CLAIMS</b> 347	<b>INDEPENDENT CLAIMS</b> 1
<b>ADDRESS</b> WAGNER, MURABITO & HAO LLP TWO NORTH MARKET STREET THIRD FLOOR SAN JOSE, CA95113					
<b>TITLE</b> Highly conductive semiconductor structures, method of forming same via plasma etch, and electrical devices incorporating highly conductive semiconductor structures					
<b>FILING FEE RECEIVED</b> 1128	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:		<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees ( Filing ) <input type="checkbox"/> 1.17 Fees ( Processing Ext. of time ) <input type="checkbox"/> 1.18 Fees ( Issue ) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit		